

## Features:

- Wide band operation from 18.0 to 40.0GHz
- High gain, medium power output, unconditional stable
- K-female connector I/O
- Single DC power supply required, built-in voltage regulator
- Operating temperature -40~+75°C, storage temperature -55~+85°C

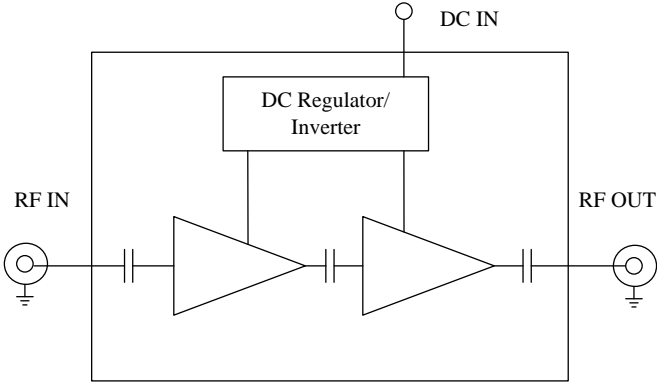
## General Description

ABP4000-45-2223 is a two stage GaAs MMIC HEMT based broadband low noise amplifier module operating in the frequency from 18.0 to 40.0GHz. The amplifier provides 22dB of small signal gain and 23dBm typical output power at 1 dB gain compression point. The amplifier requires only a single positive DC power supply. Its built-in DC voltage regulator allows the amplifier to functional at different DC supply voltages without affecting the RF performances.

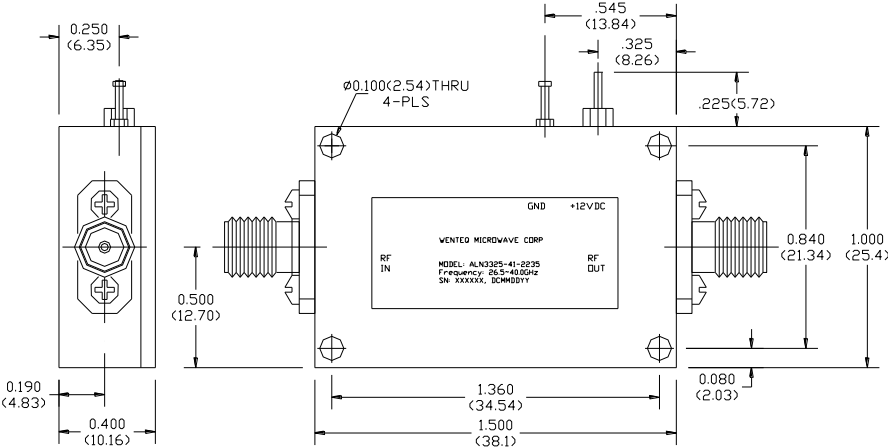
## Electrical Specifications

| Parameters                                |        | Specifications  |         |         |
|---|--------|-----------------|---------|---------|
|   |        | Minimum         | Typical | Maximum |
| Frequency Range                           | GHz    | 18.0            |         | 40.0    |
| Nominal Gain @25°C base plate temperature | dB     | 19.5            | 22.0    | 25.5    |
| Noise Figure                              | dB     |                 | 5.5     | 7.5     |
| P-1dB Compression Point                   | dBm    | +22.0           | +23.0   |         |
| Saturated Output Power                    | dBm    | +23.0           | +24.5   | +26.0   |
| Gain flatness                             | dB     |                 | +/-1.75 | +/-2.0  |
| Gain Variation over Temperature Range     | dB     |                 | +/-2.5  |         |
| Reverse Isolation                         | dB     | 55.0            |         |         |
| Input VSWR                                | -      |                 | 1.7:1   | 2.5:1   |
| Output VSWR                               | -      |                 | 1.7:1   | 2.5:1   |
| Spurious                                  | dBc    |                 |         | -70.0   |
| Operating Temperature                     | °C     | -40.0           |         | +75.0   |
| Survival Temperature                      | °C     | -45.0           |         | +125.0  |
| DC Power Supply Voltage                   | V      | +8.0            | +12.0   | +15.0   |
| DC Power Supply Current                   | mA     | 330.0           | 430.0   | 530.0   |
| RF In/Out connectors                      |        | 50 ohm k-female |         |         |
| DC Input Connector                        |        | Feedthru Pin    |         |         |
| Size                                      | inches | 1.50×1.0×0.4    |         |         |

Functional Diagram



Mechanical Structure:



Note: All units in inches (mm).

Housing Material and Surface Finish:

- Body and cover material: aluminum
- Surface finish: nickel plated
- Connector material: Stainless steel
- Connector surface finish: passivated

Absolute Maximum Ratings

|                       |            |
|-----------------------|------------|
| DC Voltage            | +18V       |
| RF Input Power        | +10 dBm    |
| Storage Temperature   | -55~+125°C |
| Operating Temperature | -40~+85°C  |



Electrostatic sensitive device, please observe precautions for handling this amplifier.